

### **BiCMOS Current Mode PWM Controller**

# B38C42/43/44/45

#### **Advance Information**

## **Description**

The Bay Linear B38C42/43/44/45 are fixed frequency and high performance current-mode PWM controller in BiCMOS. They are pin compatible with all bipolar 384X's controllers are similar to the MIC38C4X family. These devices are designed for DC-to-DC converter applications and feature a trimmed oscillator discharge current and bandgap reference.

The benefit of the BiCMOS process provides significant performance improvement compared to Bipolar 384X devices. At  $15V_{IN}$  the start-up current is reduced to  $50\mu A$  (typ.) from 0.17 mA with an operating current reduced to 4mA (typ.) from 14mA. Also, quicker output rise and fall times drive larger MOSFET 's and rail-to-rail output capability improves efficiency, especially lower supply voltages.

Major differences between members of these series are the UVLO thresholds. Typical UVLO thresholds of 14.5V (on) and 9V (off) for the B38C42 and B38C44 devices make them ideally suited to off-line applications. The corresponding typical thresholds for the B38C43 and B3845 devcies are 8.4V (on) and 7.6V (off).

The B39C4X devices are available in 8 pin DIP and SOIC.

### **Features**

- Low-Power BiCMOS Process
- Ultra Low Start-Up Current of 50µA (typ.)
- Very Lower Operating Current (4mA)
- Current Mode Operation ≥ 500KHz
- CMOS outputs with Rail to Rail outputs
- Under Voltage Lockout with Hysteresis
- 5V Trimmed Bandgap Reference
- Trimmed Oscillator Discharged Current
- Low Cross-Conduction Currents
- Available in 8 pin SOIC and 8PDip
- Similar to MIC38C42/43/44/45
- Pin to Pin compatible with UC3842X Family

## **Applications**

- Switched and Current Mode Power Supplies
- Off-line Power Supply
- Step-Up (Buck), Step-Down (Boost) Regulator
- Flyback, Isolated Regulators
- Synchronous FET converters
- Forward Converters

#### **Pin Connection**





#### 8-SOIC and 8-PDip

		Top		
RT/CT	4		5	GND
ISENSE	3		6	OUTPUT
FB	2		7	VDD
COMP	1		8	REF
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### **Ordering Information**

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Devices	Package	Temp.
B38C42M	SO-8	-40°C to +85°C
B38C42P	8-DIP	-40°C to +85°C
B38C43M	SO-8	-40°C to +85°C
B38C43P	8-DIP	-40°C to +85°C
B38C44M	SO-8	-40°C to +85°C
B38C44P	8-DIP	-40°C to +85°C
B38C45M	SO-8	-40°C to +85°C
B38C45P	8-DIP	-40°C to +85°C

# **Absolute Maximum Rating**

Parameter	Symbol	Value	Unit
Supply Voltage	$V_{\mathrm{DD}}$	20	V
Switch Supply Voltage	$V_{\mathrm{D}}$	20	V
Output Current	$I_{OUT}$	1A	A
Zener Current	$V_{ m DD}$	30	mA
Current Sense Voltage	$V_{ISENSE}$	-0.3 to 5.5	V
Feedback Voltage	$V_{FB}$	-0.3 to 5.5	V
Power Dissipation	$P_{D}$	1	W
Storage Temperature Range	T	-65 to 150	°C
Lead Temperature (Soldering 10 Sec.)	$T_{\rm L}$	300	°C

# **Electrical Characteristics**

 $V_{DD}$  = 15V (Note 4),  $R_T$  = 11k,  $C_T$  = 3.3nF,  $T_A$ = -40°C to +85°C, unless otherwise specified

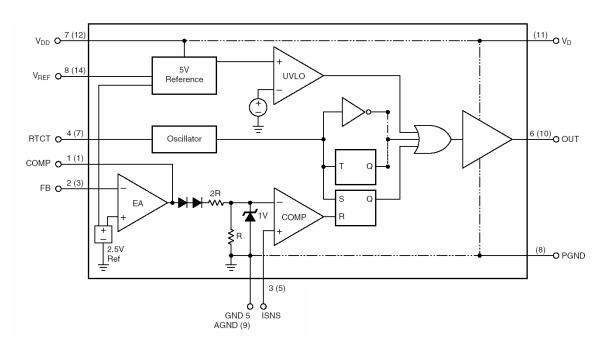
Parameter Parameter	Symbol Symbol	Conditions	MIN	TYP	MAX	UNIT
REFERENCE SECTION	REFERENCE SECTION					
Reference Voltage	$V_{REF}$	$T_J = 25$ °C. $I_{REF} = 1$ mA	4.90	5.00	5.10	V
Line Regulation	REG (LINE)	$12V \le V_{DD} \le 18V$ , $I_O = 5\mu A$	-	2	20	
Load Regulation	REG <sub>(LOAD)</sub>	1mA≤I <sub>REF</sub> ≤20mA	-	1	25	mV
Short Circuit Output Current	$I_{SC}$	T= 25 °C	-30	-80	-180	mA
OSCILLATOR SECTION	•	•	•			
Oscillator Frequency	f	T= 25 °C	47	52	57	KHz
Frequency Change with Voltage	$\Delta f/\Delta V_{CC}$	12V≤V <sub>CC</sub> ≤25V	-	0.05	1	%
Oscillator Amplitude	$V_{ m OSC}$		-	1.6	2.3	$V_{P-P}$
ERROR AMPLIFIER SECTION	N					
Input Bias Current	$I_{BIAS}$		-1	-0.1	1	μΑ
Input Voltage	$V_{I(E>A)}$	V <sub>1</sub> =2.5V	2.42	2.50	2.58	V
Open Loop Voltage Gain	$G_{VO}$	2V≤V <sub>0</sub> ≤4V	65	90	-	dB
Power Supply Rejection Ratio	PSRR	12V≤V <sub>CC</sub> ≤25V	60	70	-	dB
Output Sink Current	$I_{SINK}$	$V_2 = 2.7V, V_1 = 1.1V$	2	6	-	mA
Output Source Current	$I_{SOURCE}$	$V_2=2.3, V_1=5V$	-0.5	-1.0	-	mA
High Output Voltage	$V_{OH}$	$V_2 = 2.3$ , $R_L = 15\Omega$ to GND	5	6	-	V
Low Output Voltage	$V_{OL}$	$V_2 = 2.7$ , $R_L = 15\Omega$ to pin 8	-	0.8	1.1	V
OUTPUT SECTION						
Low Output Voltage	$V_{\mathrm{OL}}$	$I_{SINK} = 20 \text{mA}$		0.08	0.4	V
	V OL	$I_{SINK} = 200 \text{mA}$	_	1.4	2.2	v
High Output Voltage	$V_{\mathrm{OH}}$	$S_{ource} = 20 \text{mA}$	13	13.5	-	V
	· On	$S_{ource} = 200 \text{mA}$	12	13.0	-	Ţ
Rise Time	$t_R$	$T_J = 25 \text{ °C}, C_L = 1 \text{ nF (note3)}$	-	40	70	ns
Fall Time	$t_{\mathrm{F}}$	$T_J = 25  ^{\circ}\text{C},  C_L = 1  \text{nF (note3)}$	-	30	50	ns

Note: Output Switch tests are performed under pulsed conditions to minimize power dissipation

### **Electrical Characteristics**

 $(V_{CC} = 15V; R_T = 10\Omega, C_T = 3.3nF, T_A = 0 \degree C \text{ to } +70\degree C, \text{ unless otherwise specified})$ 

Parameter	Symbol	Conditions	MIN	TYP	MAX	UNIT
CURRENT SENSE SECTION						
Gain	$G_{V}$	(Note 1 & 2)	2.85	3	3.15	V/V
Maximum input Signal	$V_{I(MAX)}$	$V_1 = 5V \text{ (Note 1)}$	0.9	1	1.1	V
Power Supply Rejection Ratio	PSRR	12V≤V <sub>CC</sub> ≤25V		70	-	dB
Input Bias Current	$I_{BIAS}$			-3	-10	μΑ
UNDER-VOLTAGE LOC	KOUT SEC	TION				
Start Threshold	V	B3842/B3844	14.5	16	17.5	V
Start Threshold	$V_{TH(ST)}$	B3843/B3845	7.8	8.4	9	
Min-Operating Voltage	V	B3842/B3844	8.5	10	11.5	V
(after Turn On)	(after Turn On) $V_{OPR(MIN)}$	B3843/B3845	7.0	7.6	8.2	V
PWM SECTION	PWM SECTION					
Max Duty Cycle	D(MAX)	B3842/B3844	95	97	100	%
Max Duty Cycle	D(MAA)	B3843/B3845	47	48	50	70
Min Duty Cycle	D (MIN)		-	•	0	%
TOTAL STANDBY CURRENT						
Start-Up Current	$I_{ST}$	B3842A/43A/44A/45A	-	100	120	μA
Start-Op Current		B3842B/43B/44B/45B		100	120	μΑ
Operating Supply Current	$I_{CC(OPR)}$	$V_3=V_2=ON$	-	14	17	mA
Zener Voltage	$V_Z$	$I_{CC}$	30	38	-	V
Start-Up Current	$I_{ST}$	B3842A/43A/44A/45A	-	0.17	0.3	mA
PACKAGE THERMAL RESISTANCE						
8-SOIC	$\theta_{ m JA}$				170	°C/W
8-PDip	$\theta_{\mathrm{JA}}$				125	°C/W



Startup & Operating Voltage Selection Guide

	UVLO Thresholds		
<b>Duty Cycle</b>	Star-Up at 8.4V Operating Min= 7.6V	Star-Up at 14.5V Operating Min= 9.0V	
0% to 96%	B38C43	B38C42	
0% to 50%	B38C45	B38C44	

**Pin Descriptions** 

Pin No.#	Name	Function
1	COMP	Output of error amplifier & input to PWM comparator
2	FB	Inverting input of error amplifier
3	ISNS	Current sense comparator input. It is internally limited to 1V
4	RT/CT	Oscilator RC timing component connection. Resistor RT is connected to
		V <sub>REF</sub> and capacitro CT is conencted to ground. Different values of RT
		and CT determine the maximum duty cycle
5	GND/PGND	Combined pwoer and analog ground
6	OUT	High-power, toten-pole driver output. OUT pin is activly held LOW
		when V <sub>CC</sub> is below the UVLO threshold.
7	$V_{\mathrm{DD}}$	Suply votlage input
8	$ m V_{REF}$	5Volt reerence votlage output

# **Application Notes:**

The Bay Linear B38C4X devices are compatible with generic 384x PWM devices. The following discussion highlights the differences and advantages of the Bay C design.

#### Start- up Current

Bau Linear BiCMOS process allows for substantial reduction in the start- up current. Typical start- up current is 95  $\mu$  A, with a maximum limit of 120  $\mu$  A. Low start- up current allows high resistance, lowerwattage, start- up resistors to supply controller start-up power.

### **Output Driver**

The B38C4x CMOS output stage drives external power MOSFETs to the full supply voltage. Low ON-resistance and high peak current drive combine to give greater than 1000pF gate capacitance drive capability. Rise and fall time requirements may dictate the appropriate value of output capacitance. Within the restrictions of output capacity and controller power dissipation, switching frequencies

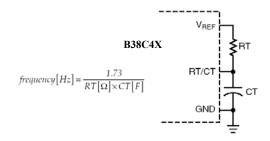
can exceed 1MHz.

The CMOS output stage "break-before-make" action is guaranteed by design and insures that no cross-conduction current will flow. This minimizes heat dissipation, increases efficiency and enhances reliability.

#### **Oscilator Operation**

Two external components, RT and CT, set the switching frequency.

With VCC = 14V, RT = 10k and CT = 3.3nF, nominal switching frequency is 50kHz.



Advance Information- These data sheets contain descriptions of products that are in development. The specifications are based on the engineering calculations, computer simulations and/ or initial prototype evaluation. Preliminary Information- These data sheets contain minimum and maximum specifications that are based on the initial device characterizations. These limits are subject to change upon the completion of the full characterization over the specified temperature and supply voltage ranges. The application circuit examples are only to explain the representative applications of the devices and are not intended to guarantee any circuit design or permit any industrial property right to other rights to execute. Bay Linear takes no responsibility for any problems related to any industrial property right resulting from the use of the contents shown in the data book. Typical parameters can and do vary in different applications. Customer's technical experts must validate all operating parameters including "Typical" for each customer application. LIFE SUPPORT AND NUCLEAR POLICY

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